Theory for Slightly D oped Antiferrom agnetic M ott Insulators

T.K.L $ee^{1,2}$, Chang-M ing H o^2 , N acto N agaosa^{3,4} and W ei-Cheng L ee^{1}

¹ Institute of Physics, Academ ia Sinica, Nankang, Taipei, Taiwan 11529

² Physics Division, National Center for Theoretical Sciences, P.O. Box 2-131, H sinchu, Taiwan

300

³ Department of Applied Physics, University of Tokyo, 7-3-1 Hongo, Bunkyo-ku, Tokyo 113-8656,

Japan

⁴ Correlated Electron Research Center, A IST, T sukuba, Ibaraki 303-0046, Japan (September, 2002. For the M O S2002 proceedings.)

Abstract

Trial wavefunctions, constructed explicitly from the unique 2-dimensional M ott insulating state with antiferrom agnetic order, are proposed to describe the low-energy states of a M ott insulator slightly doped with holes or electrons. W ith the state behaving like charged quasi-particles with well-de ned m on enta, a rigid band is observed. These states have m uch less pairing correlations than previously studied ones. Sm all Ferm i patches obtained are consistent with recent experiments on high T_c cuprates doped lightly with holes or electrons. States show ing the incoherent and spin-bag behaviors are also discussed. U sing these wavefunctions, a number of results obtained by exact calculations are reproduced.

PACS: 74.72 Jt, 75.50 Ee, 79.60.-i

Typeset using REVT_EX

W ith the continuous in provement of experimental technique and sample making, it has recently become possible to study in detail the phenomena in the lightly doped high T_c cuprates. Indeed, many intriguing behaviors concerning the physics of doping the two-dimensional(2D) M ott insulator in this very undedoped regime are observed. Recent angle-resolved photoemission spectroscopy (ARPES) results unearth contrasting behaviors between lightly hole-doped C a_2 $_zN a_zC uO_2C l_2$ (N a-CCOC) [1] and electron-doped N d_2 $_xC e_xC uO_2$ (NCCO) high T_c cuprates [2]. Although ARPES on the undoped (i.e. z=x=0) insulating state shows an identical energy dispersion of a single hole created below the charge gap, results at a little higher dopings are demonstrated to be di erent: while a small hole patch is observed to be centered clearly at momentum (/2, /2) in the N a-CCOC at even z=0.1, sm all electron patches centered at (,0) and (0,) are observed for x=0.04 in NCCO. Moreover, the in-plane transport in lightly doped systems shows high m obility of the charge carriers [3]. This and the recent high-resolution scanning tunneling microscopy/spectroscopy results indicate the signature of the quasi-particle behavior [4].

The single hole/electron behavior and its dispersion have been studied using various approaches on the $t+t^0+t^{0-}J$ m odel [5{10]. However, these studies on doping holes and electrons into the system only emphasize the asymmetry resulting from the dimenstation of t and t^{0} for the corresponding H am iltonians. It is unclear whether the same physics is working for these two systems with dimenstry H am iltonians. Should one try to construct a dimenstry theory when electron-doped cuprates are considered? Furthermore, do the models predict sm all Ferm i surfaces and quasi-particles?

There are other issues concerning them odel itself which have been bothersom e. The studies applying the projected d-wave superconducting, or the resonating-valence-bond (RVB), state with the antiferrom agnetic long range order (AFLRO) also suggest that away from half-lling, the superconductivity (SC) revives and the ground state shows both SC and AFLRO [13,14]. But so farm ost experiments do not support the coexistence. In addition, there has been not enough understanding on various properties found in the exact results of the t-J type m odels on nite clusters [5,6,8{12}] in term s of the m any-particle wave functions (W F's).

In this paper, we discuss our recent proposal of a theory based on the variational approach to understand these issues [15,16]. Speci c trial wavefunctions (TW F's) are constructed to describe both the low-energy states of the associated $t+t^0+t^0-J$ m odels with lightly doped holes and electrons. These W F's are generalizations of the single-hole W F rst written down by Lee and Shih [7]. In contrast to other TW F's [17], ours are constructed solely from the optimized one at half-lling and include no hopping am plitudes t and t^0 . Yet, supprisingly, a number of properties including dispersion relations, m on entum distributions, spectral weight etc. are obtained connectly for both hole-doped and electron-doped systems. In the following, the Lee-Shih W F for one doped hole is used and generalized for several holes as well as electron-doped systems. All numerical results reported below are from variational M onte C arbo (VM C) calculations for an 8 8 lattice with periodic boundary conditions.

At half-lling, the system is described by the Heisenberg Hamiltonian

$$H_{J} = J_{\text{hirij}}^{X} (S_{i} \quad S_{j} \quad \frac{1}{4} n_{i} n_{j}); \qquad (1)$$

where hi; ji denotes nearest-neighbor (n n;) sites. Each site is occupied by only one single electron. As holes or electrons are doped into the system, we consider the H am iltonian $H = H_{t-t^0} t^{t_0} + H_J$ including n n; and longer range hoppings. Here $H_{t-t^0} t^{t_0} = t^{P}_{hi;ji}$ $e_i^{y} e_j = t^{0^{P}}_{hi;ii} e_i^{y} e_1 = t^{0^{P}}_{hi;m,i} e_i^{y} e_m + H c.$ with hi; li and hi; m i representing the second n n; and third n n; site pairs. Note that e_i in $H_{t-t^0} t^{t_0}$ creates dimensioned doping and two-electron-occupied sites at half-lling; empty holes (0e-hole) for hole doping and two-electron-occupied holes (2e-hole) for electron doping [18]. Operator e_i is actually equal to e_i (1 $n_{i;}$) or $e_{i;}$ n_i for hole or electron doped case, respectively. Therefore, despite the constraints, states in the two cases are in one-to-one correspondence after a local transform ation e_i ! $e_{i;}^{y}$ is made. However, because of the Ferm i statistics, the exchange of a single spin with a 2e-hole has an extra m inus sign as compared to the 0e-hole. Hence, the only dimensioned between the hole-doped and electron-doped t $-t^{0}t^{0}-t^{0}$ m odel is $t^{0}-t$! $t^{0}-t$ after we change the e_i on B sublattice sites to e_i [5]. W ith all these, we then treat the hole and electron doped cases in the sam e m anner with the Lee-Shih W F originally proposed only for a single hole. The VM C results presented in this paper are for J=t = 0.3, $t^0=t = (+)0.3$ and $t^{00}=t = +()0.2$ in the hole (electron) doped case following the values usually used [5].

W e shall apply the standard VMC m ethod [17] that enforces the local constraint exactly. Following the work by Lee and Shih [7], the TWF for one doped hole with momentum q and $S_z = 1=2$ is constructed to have (N_s=2) 1 singlet pairs of electrons and a single unpaired electron with momentum q and $S_z = 1=2$,

$$j_{1}i = P_{d} c_{q''}^{y} [\sum_{k}^{X} (A_{k} a_{k''}^{y} a_{k''}^{y} + B_{k} b_{k''}^{y} b_{k''}^{y})]^{(N_{s}=2)}]^{1}$$

The prime on the summation symbol indicates that the momentum q is excluded from the sum if q is within the sublattice Brillouin zone (SBZ), otherwise, q = Q is excluded. N_s here is the total number of sites and Q = (;).

j₁i is explicitly constructed from the optimized half-lled WF j₀i = $P_d \begin{bmatrix} P \\ k \\ A_k a_k^y a_k^y a_k^y + B_k b_k^y b_{k+}^y \end{bmatrix}^{N = 2}$ joi and it does not contain any information about hoppings, t⁰, t⁰ and neither explicitly t, of the doped hole or electron. However, the e ect of t is included in the RVB uniform bond = h^P c_1^y c_j i which describes the large quantum uctuation and spin singlet formation. There is also no need to introduce t⁰ and t⁰⁰ in the TWF as they are compatible with AFLRO. Here the coe cients A_k and B_k are functions of k and k. $k = (\frac{2}{k} + (Jm_s)^2)^{\frac{1}{2}}$ are energy dispersions for the two spin density wave (SDW) bands with $k = \frac{3}{4}J$ (cosk_x + cosk_y) and the staggered magnetization $m_s = hS_A^z i = hS_B^z i$, where the lattice is divided into A and B sublattices. a_k and b_k represent the operators of the lower and upper SDW bands, respectively, and are related to the original electron operators Q_k and Q_{k+Q} with Q = (; ;) set for the commensurate SDW state. $k = \frac{3}{4}J$ d_k with $d_k = cosk_x$ cosk_y here is for the d-wave RVB (d-RVB) order parameter. The projection operator P_d enforces the constraint of no doubly occupied (or vacant) sites for cases with

nite hole (or electron) doping . At half- lling, N equals the total number of electrons. Notice that the sum in j₀i is taken over SBZ. There are two variational parameters: = and $m_s = in$ these W F's.

The energy dispersion obtained from j₁i for one doped hole has been shown by Lee and Shih [7] to agree very well with that of exact calculations, self-consistent Born approxim ations (SCBA), and G reen function M onte C arlo m ethods etc.. As for the case of having an extra up-spin electron with m om entum q doped into the half-lied state, the energy dispersion can be calculated with this sam e W F j₁i. The only di erence is signs of that and t⁰ are changed in the H am iltonian.

The variational energies for one doped electron are shown as black dots in Fig.1. This result agrees well with that of X iang and W heatley [6] obtained by SCBA. The optim al variational parameters are $(= ;m_s =) = (0.25, 0.125)$. The ground state is at momentum q = (;0). The VMC results can be tted simply by $E_{1k} = E_k - 2t_{eff} (\cos k_x + \cos k_y)$ $4t_{eff}^0 \cos k_x \cos k_y - 2t_{eff}^0 (\cos (2k_x) + \cos (2k_y))$ with parameters described in the caption of Fig.1. The dispersion thus seems to be simply the combination of the mean-eld band at half- lling and the coherent hoppings [7].

To exam ine further the physical properties of j₁i, we calculated the momentum distribution function hn^h (k) i for the ground state of a single hole with momentum q = (=2; =2) and $S_z=1=2$. Results are shown in Fig2(a) and (b). Note that the dips or pockets at (=2; =2) and anti-dips at (=2; =2) found by Leung [10] for the exact results of 32 sites are also clearly seen here. It is quite am azing that j₁i, including no t⁰ and t⁰, not only produces the correct energy dispersions for a single doped hole or electron it also provides a correct picture about the momentum distribution.

The momentum distribution functions $hn^e(k)i$ for electron doped systems could be also calculated from j₁i if we perform the transformation, $c_i ! c_{i;}^v$, and t is chosen to be positive. In fact, it is easy to show that $hn^e(k)i = 1$ $hn^h(Q)(k)i$. The results for the ground state of a single doped electron with momentum k = (;0) and spin $S_z = 1 = 2$ are shown in Fig.2 (c) and (d). There are peaks at k = (;0) and an anti-peak at k = (0;).

Now we shall generalize the Lee-Shih W F j $_1$ i to the case of two holes. The simplest possible way is just to take out the unpaired spin from j $_1$ i if we are interested in the state

with zero total momentum and $S_z = 0$, which turns out to be the lowest energy state. The TW F for two holes with momenta q and q is

$$j_{2}i = P_{d} \begin{bmatrix} X & 0 \\ k & a_{k}^{y} a_{k}^{y} a_{k}^{y} + B_{k} b_{k}^{y} b_{k}^{y} b_{k}^{y} \end{bmatrix}^{(N_{s}=2)} 1 j0i$$

Note that the momentum q is not included in the summation. It is most surprising to d that although j₂i has zero total momentum irrespective of q, its energy varies with the missing momentum or the hole momentum q. The dispersion turns out to be very similar to that of a single electron as shown in Fig.1 [15]. The state with momentum q = (; 0) has the lowest energy for two electrons. The values of the two parameters = and m_s = are the same for j₂i and j₁i.

Using W F j ₂i, the energy dispersion for two holes doped into the half- lled state again has an almost identical form as that of a single hole and the minimum is at q = (=2; =2)[7]. The lowest energy obtained is 26:438 (3)t which is much lower than the variational energy, 25:72 (1)t, using the TW F applied by H in eda and O gata [14]. Even if we include t⁰ and t⁰, the variational energy 25:763 (7)t, is still much higher than ours [19]. W e also found that the hopping am plitudes for n n:, second n n: and third n n: of two holes are almost twice that of one hole. The momentum distribution function for this state (not shown) has dips at (=2; =2) and (=2; =2). This is in good agreement with the exact result [10] for the t-t⁰-t⁰-J m odel with 2 holes in 32 sites.

It is then straightforward to write down the same type of TW F for three holes with momenta q, q^0 and q^0 :

$$j_{3}i = P_{d} c_{q}^{y} [[A_{k} a_{k}^{y} a_{k}^{y} + B_{k} b_{k}^{y} b_{k}^{y}]^{N_{s}=2}]^{2} j 0 i;$$

where q^0 and q are excluded from the summation. Just like the case with two holes or two electrons energy dispersions are proportional to the sum of the three single hole energies at momenta q, q^0 and q^0 . In Fig.3, the dispersions are plotted as functions of q. For the electron doped (i.e. with three 2e-holes) case in Fig.3 (a), the lowest energy state is at q = (3 = 4; 0) (shown as an open circle) within the SBZ after the state of electrons occupy $q^0 = (;0)$. W ith three doped holes (Fig.3(b)), after the two electrons at (=2; =2) are removed the ground state is now at (=2; =2) (the open circle). As shown clearly in Fig.3, the dispersions follow nicely the single hole one.

Values of the staggered m agnetization $m = N_s^{1^P}_i (1)^i S_i^z$ are computed and compared for several 0e-hole and 2e-hole concentrations. W ith the same variational parameters, it is found that the preference of (=2; =2) for 0e-holes causes clearly larger disturbance of the AF order than for the electron doped case where 2e-holes with momentum (;0) shows much less in uence on the AF order [15]. This is consistent with previous work [5]. It is also consistent with experimental results that AF phase is more stable for electron doping than hole doping [20].

So far, based on the t-t⁰-t⁰-J m odel we have proposed a TW F to describe the low energy states of slightly doped antiferrom agnetic M ott insulators. Exactly the same TW F's are proposed to account for the behavior of both hole doping and electron doping, after we employed the particle-hole transform ation. D i erent energy dispersions for these two cases are due to the di erent signs of f=t and t⁰=t which is a direct consequence of the constraint that electron doped system has 2e-holes while hole doped system only has 0e-holes. R igid band and quasi-particle behavior are demonstrated for both cases. The theory provides an explanation of recent ARPES results. In lightly hole-doped cuprates, sm all Ferm ipocket is around (=2; =2). In electron-doped cuprates, the patch is around (; 0) as shown in the inset of Fig.1 with doping at about 3%.

Another important property of our W F's is that holes are essentially independent of each other as they obey the same energy dispersions (with very little renorm alization of parameters). Exactly because this quasi-particle like property is unchanged after doping, our W F has AFLRO but very little superconducting pairing correlations. The presence of superconducting state certainly will change the excitation spectra. In particular, the d-wave SC, which coexists with AFLRO in some of the previous variational studies, should have low energy excitations along the nodes. This is certainly not seen in our TW F's. In addition, the holes are not attractive to each other in our W F's. In Fig.4 the hole-hole correlation function for our TW F and the W F used by authors in [14] are compared for 4 holes in an 8 8 lattice. The lack of attraction between holes is consistent with Leung's low energy states obtained exactly for two holes in 32 sites [10]. Long range d-wave pairing correlation de ned [17] for our TW F and that in H in eda-O gata one are, on average, about 0:002, and 0:018, respectively. Thus the d-RVB pairing for spins assumed by our W F's are not in any way in plying the pairing of charges.

A lihough our TW F's or the Lee-Shih W F's has reproduced m any numerical results obtained by exact diagonalization, SCBA, etc. for one or two holes or electrons, there exists, however, some inconsistancy in the detail of the comparison. Namely, at some m om enta k's the spectral weights $Z_k = j_{k} j_{k} j_{0} i j_{-}^{2} = h_{0} j_{k}^{V} q_{k} j_{0} i$ computed for the one doped hole case using $j_{k}i = j_{-1}i$ are much larger than the exact results [8]. This m ay indicate that the quasi-particle states do not exist everywhere in the Brillouin zone. In fact, the ARPES on the undoped (z = 0) N a-CCOC also show well-de ned peaks only locally in the high-symmetry directions [1].

W e have constructed TW F's with which sm all spectral weights are realized at particular k points [16]. For the single hole doped case, state described by W F

$$j_{1}^{0}i = P_{d} c_{q_{s}"}^{y} [\sum_{k \in q_{h}]}^{X} (A_{k} a_{k}^{y} a_{k}^{y} + B_{k} b_{k}^{y} b_{k}^{y} b_{k}^{y})]^{(N_{s}=2)}]^{1} Di$$

with the hole m om entum $q_h = (=2; =2)$ has also one singlet bond less than the half-led case, but the unpaired spin m om entum q_s is chosen here not to be the same as q_h . Note that only q_h is excluded within the sum for j_1^0 i. W ith the same parameters = and $m_s =$, it is found that j_1^0 i can have lower variational energy than that of the quasi-particle state j_1 i at some q_s 's. Apparently, m any states could be constructed with same q_s but dimension q_h . These states constitutes the continuum at higher energy.

Substituting W F j ${}_{1}^{\circ}$ i and the quasi-particle j ${}_{1}$ i into j ${}_{k}$ i and computing Z_k su ces to reproduce the variation of the spectral weights obtained in the exact results [8]. States described by j ${}_{1}^{\circ}$ i have sm aller Z_k's and are thus with a strong incoherent character. W e also found that m ore quasi-particle states have lower energy below the continuum in the pure t-J model with $t^0 = t^{00} = 0$ [11] than in the t-t⁰-t⁰⁰-J model. This is consistent with what has been known in the exact results [8].

To understand the incoherent states m ore, the hole-spin correlations for $j_1^{\circ}i$ with different q_s 's are examined [16]. The spin congurations around the hole are quite dimentified in that of the quasi-particle states. Spin m on ents around the hole in the quasi-particle state $j_{11}i$ can have values larger than the average at that m on entum, thus the unpaired spin seem s to be bound to the hole. However, in the incoherent state the staggered magnetization is suppressed around the hole, this is like a spin-bag state [21]. The unpaired spin is no longer associated with the hole and this is now a spin-charge separated state. The am azing dimense between these two wave functions could be understood quite easily. When we apply the spin ipping operator, $S'(\cdot) (k^{\circ}; q^{\circ} = q \models q_h) = \prod_{q=0}^{P} q^{\circ} c_{q^{\circ}+k^{\circ}m}^{q} (p) q_{q^{\circ}+k^{\circ}m}^{\circ} (p)$

In sum mary, we have discussed new TW F's describing the low-energy states of the t^{0} -J m odel at lightly doping. These states reproduce various exact num erical results and, also, show consistent behaviors with what have been observed in the experiments. We are grateful to Drs. A. Dam ascelli, F. Ronning and Prof. Z.-X. Shen for sharing their ARPES data prior to publication, and Profs. C.-T. Shih and P.W. Leung for some supporting results and invaluable discussions. TKL is supported by the grant NSC 89-2112-M-001-103 (R O C.) and NN is supported by Priority A reas G rants and G rant-in-A id for COE research from the M inistry of Education, Culture, Sports, Science and Technology of Japan.

9

REFERENCES

- [1] A.Dam ascelli, Z.-X. Shen and Z.Hussain, cond-m at/0208504; F.Ronning et al., Science 282, 2067 (1998); Y.K ohsaka et al., cond-m at/0209339; F.Ronning et al., unpublished.
- [2] N.P.Am itage et al, Phys. Rev. Lett. 88, 257001 (2002).
- [3] Forhole-doped system s, see, e.g., Y. Ando, K. Segawa, A. N. Lavrov and S. Kom iya, this proceeding; for electron-doped one, Y. Onose, Y. Taguchi, K. Ishizaka and Y. Tokura, Phys. Rev. Lett. 87, 217001 (2001).
- [4] J.E.Ho man, et al., Science 297, 1148 (2002); C.Howald et al., cond-mat/0208442.
- [5] T. Tohyam a and S. Maekawa, Phys. Rev. B 49, 3596 (1994); R. J. Gooding, K. J. E. Vos and P.W. Leung, Phys. Rev. B 50, 12866 (1994).
- [6] T.X iang and J.M.W heatley, Phys. Rev. B 54, R12653 (1996).
- [7] T.K.Lee and C.T.Shih, Phys.Rev.B 55, 5983 (1997).
- [8] P.W. Leung, B.O. Wells and R.J.Gooding, Phys. Rev. B 56, 6320 (1997).
- [9] T Tohyam a et al, J. Phys. Soc. Jpn. 69, 9 (2000).
- [10] P.W. Leung, Phys. Rev. B 65, 205101 (2002) and private communications.
- [11] P.W. Leung and R.J.Gooding, Phys. Rev. B 52, R15711 (1995).
- [12] A.L.Chernyshev, P.W. Leung and R.J.Gooding, Phys. Rev. B 58, 13594 (1998).
- [13] T.K.Læ, and S.P.Feng, Phys.Rev.B 38, 11809 (1988); G.J.Chen et al, Phys.Rev. B 42, 2662 (1990).
- [14] A.H im eda and M.Ogata, Phys. Rev. B 60, R 9935 (1999).
- [15] T.K.Lee, C.M. Ho and N.Nagaosa, unpublished.
- [16] W.-C.Lee, T.K.Lee and C.-M.Ho, unpublished.

- [17] For the introduction and early work of VW F study, see C.G ros, Ann.Phys. (New York) 189, 53 (1989); also see, for the more recent, e.g., H.Yokoyam a and M.Ogata, J.Phys. Soc. Jpn. 65, 3615 (1996).
- [18] D.G.Clarke, Phys. Rev. B 48, 7520 (1993).
- [19] A ctually, the lowest energy for H in eda-O gata type TW F is obtained when its param eters are chosen to replicate our TW F.D etails are to be reported elsewhere.
- [20] H. Takagi, Y. Tokura and S. Uchida, Physica C 162-164, 1001 (1989); ibid., Phys. Rev. Lett. 62, 1197 (1989); G. M. Luke et al., Phys. Rev. B 42, 7981 (1990); K. Yam ada et al., J. Phys. Chem. Solids, 60, 1025 (1999).
- [21] J.R.Schrie er, X.G.W en and S.C.Zhang, Phys. Rev. Lett. 60, 944 (1988).

FIGURES

FIG.1. Energy dispersion of one electron in the $t+t^0+t^{00}-J$ model on an 8 8 lattice. B lack dots are VMC results by using j₁i. The tted dispersion E_{1k} E₀ are plotted as gray diam onds with parameters = 6:92, = 2:71, m_s = 18:84, E₀ = 7:43, t_{eff} = 0:06, t_{eff}⁰ = 0:15, t_{eff}⁰ = 0:1. Inset: patches in one of BZ by lling the tted dispersion in the main gure up to 3% doping.

FIG.2. Momentum distribution functions $\ln^{h(e)}(k)$ i for a single hole, (a) and (b), and electron, (c) and (d), in the 8 8 t t⁰ t⁰ J model. A scale is shown in between each set. The darker area indicates sm aller values of $\ln^{h(e)}(k)$ i.

FIG.3. Energy dispersions of (a) three doped electrons and (b) three doped holes in the $t+t^0+t^0-J$ model. Filled circles are VMC results for the momenta shown along the horizontal axis by using j₃i. A total minus sign has been multiplied to the hole doped case. Open circles, with the momenta also displayed, represent the lowest energy states. Results here are obtained with parameters shown in the gures.

FIG. 4. Hole-hole correlation functions with 4 doped holes in the 8 8 lattice. The result obtained using our W F, i.e. same form as j₂i with momenta (/2, /2) and (/2, /2) excluded in the sum, is compared with that using the H in eda-O gata W F. Results here are obtained with optimized parameters (=; m_s=) = (0.25, 0.125) and, for H in eda-O gata one, also = -0.025.

This figure "1e-disp.jpg" is available in "jpg" format from:

This figure "3eh-disp.jpg" is available in "jpg" format from:

This figure "4h-hh.jpg" is available in "jpg" format from:

This figure "nk1-eh-c.jpg" is available in "jpg" format from: